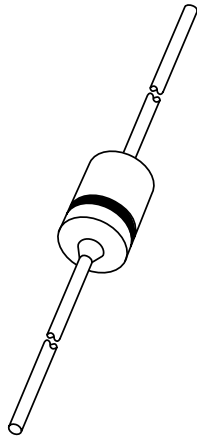


# DATA SHEET



## **BAX18** General purpose diode

Product specification  
Supersedes data of April 1996

1996 Sep 18

# General purpose diode

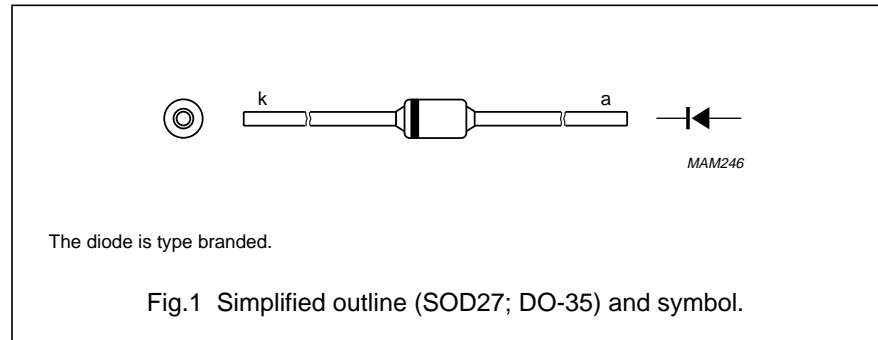
# BAX18

## FEATURES

- Hermetically sealed leaded glass SOD27 (DO-35) package
- Switching speed: max. 50 ns
- General application
- Continuous reverse voltage: max. 75 V
- Repetitive peak reverse voltage: max. 75 V
- Repetitive peak forward current: max. 2 A.

## DESCRIPTION

The BAX18 is a general purpose diode fabricated in planar technology, and encapsulated in the hermetically sealed leaded glass SOD27 (DO-35) package.



## APPLICATIONS

- Rectifier applications.

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{RRM}$	repetitive peak reverse voltage		–	75	V
$V_R$	continuous reverse voltage		–	75	V
$I_F$	continuous forward current	see Fig.2; note 1	–	500	mA
$I_{FRM}$	repetitive peak forward current		–	2000	mA
$I_{FSM}$	non-repetitive peak forward current	square wave; $T_j = 25\text{ °C}$ prior to surge; see Fig.4 $t = 1\ \mu\text{s}$ $t = 100\ \mu\text{s}$ $t = 10\ \text{ms}$	–	55 15 9	A A A
$P_{tot}$	total power dissipation	$T_{amb} = 25\text{ °C}$ ; note 1	–	450	mW
$T_{stg}$	storage temperature		–65	+200	°C
$T_j$	junction temperature		–	200	°C

## Note

1. Device mounted on an FR4 printed circuit-board; lead length 10 mm.

## General purpose diode

BAX18

**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ °C}$ ; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_F$	forward voltage	see Fig.3 $I_F = 300\text{ mA}$	–	1.0	V
		$I_F = 2\text{ A}; T_j = 150\text{ °C}$	–	1.5	V
$I_R$	reverse current	see Fig.5 $V_R = 75\text{ V}$	–	5	$\mu\text{A}$
		$V_R = 75\text{ V}; T_j = 150\text{ °C}$	–	100	$\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}; V_R = 0$ ; see Fig.6	–	35	pF
$t_{rr}$	reverse recovery time	when switched from $I_F = 30\text{ mA}$ to $I_R = 30\text{ mA}; R_L = 100\ \Omega$ ; measured at $I_R = 3\text{ mA}$ ; see Fig.7	–	50	ns

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length 10 mm	240	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	lead length 10 mm; note 1	375	K/W

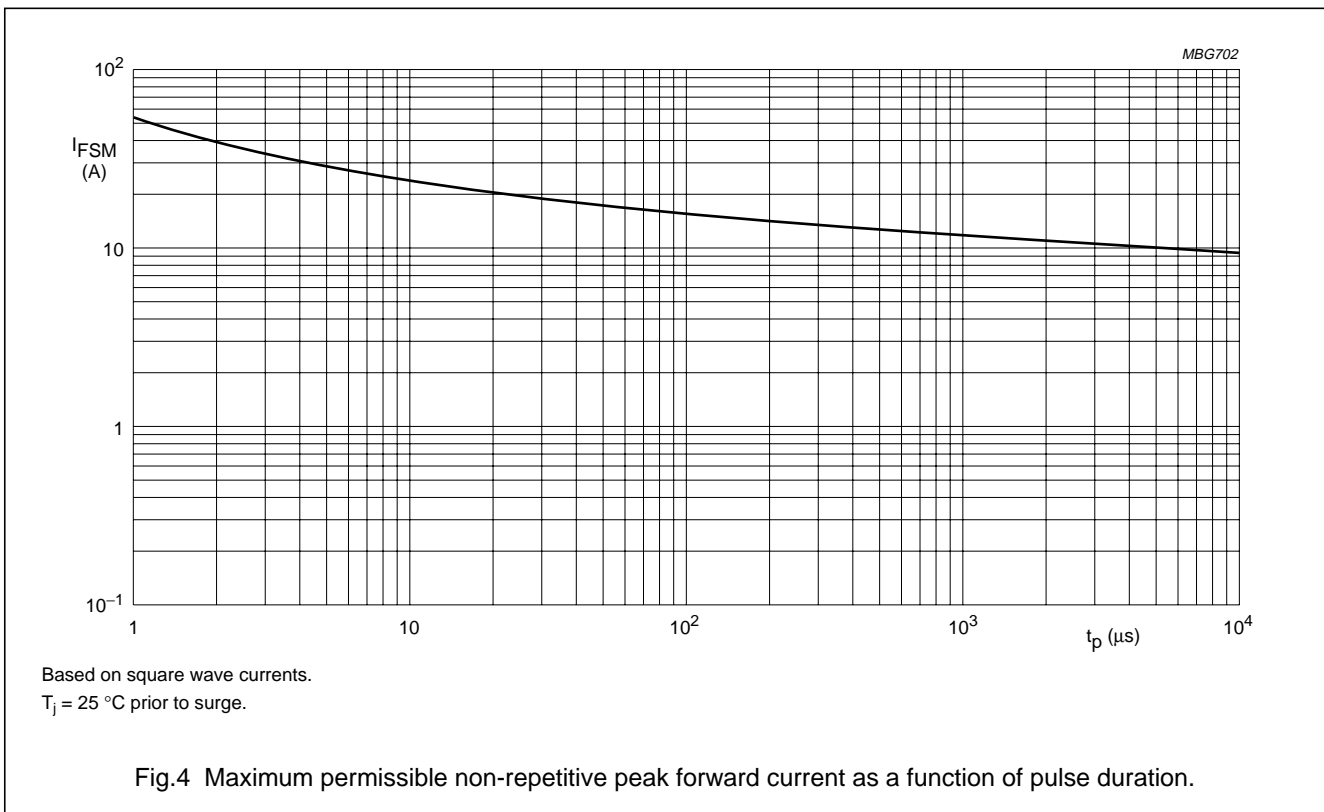
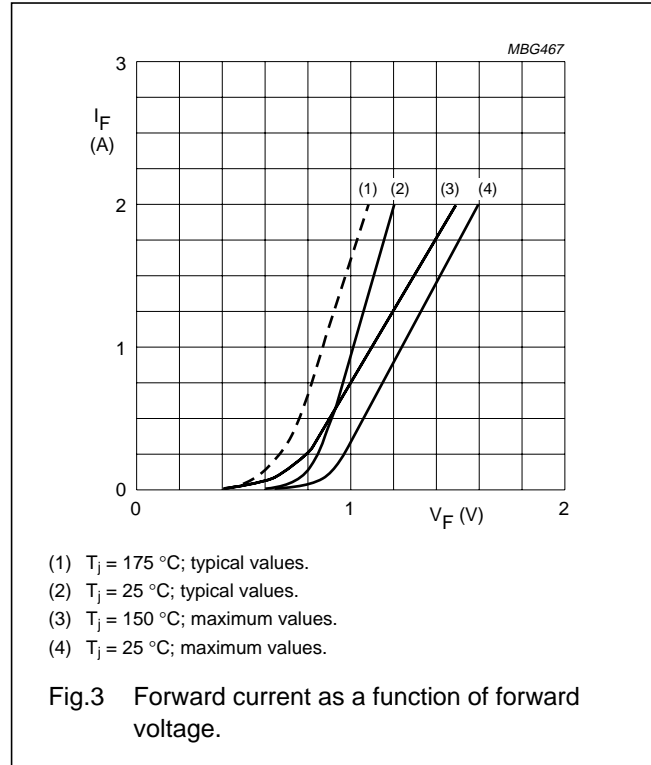
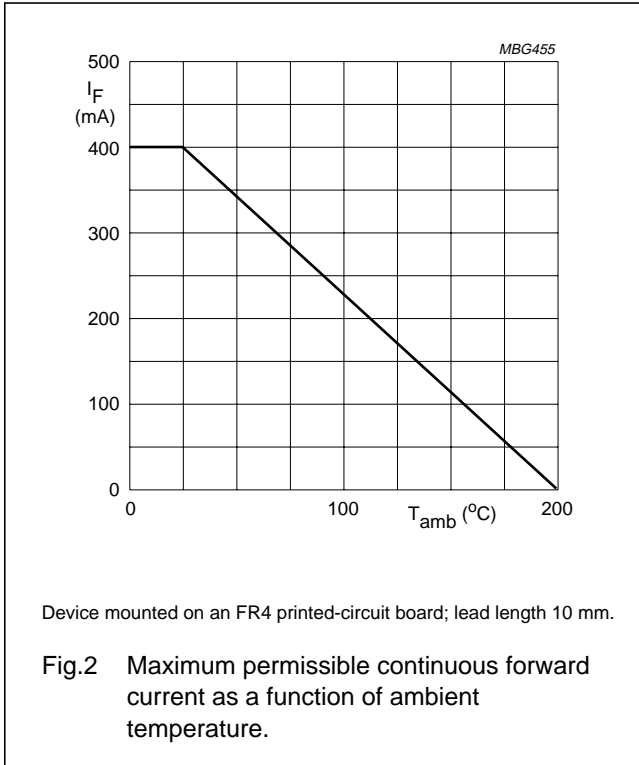
**Note**

1. Device mounted on a printed circuit-board without metallization pad.

General purpose diode

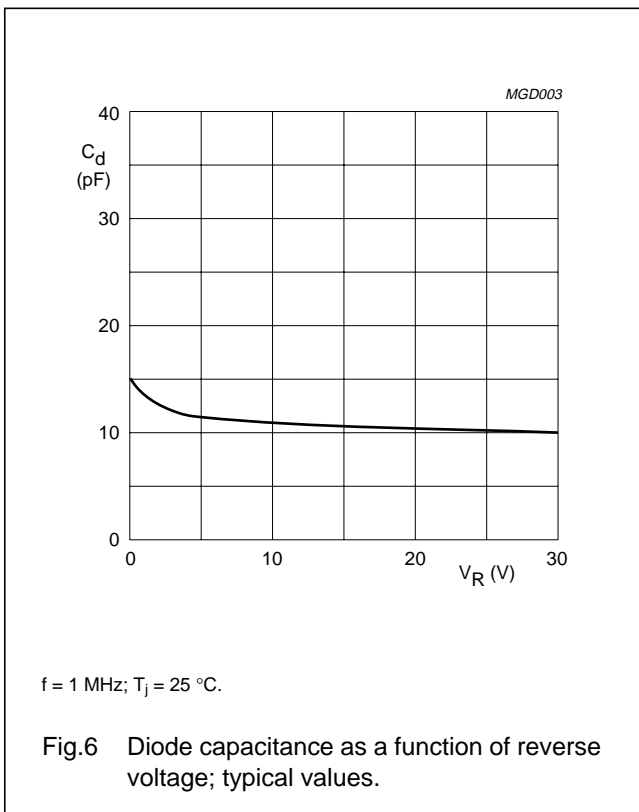
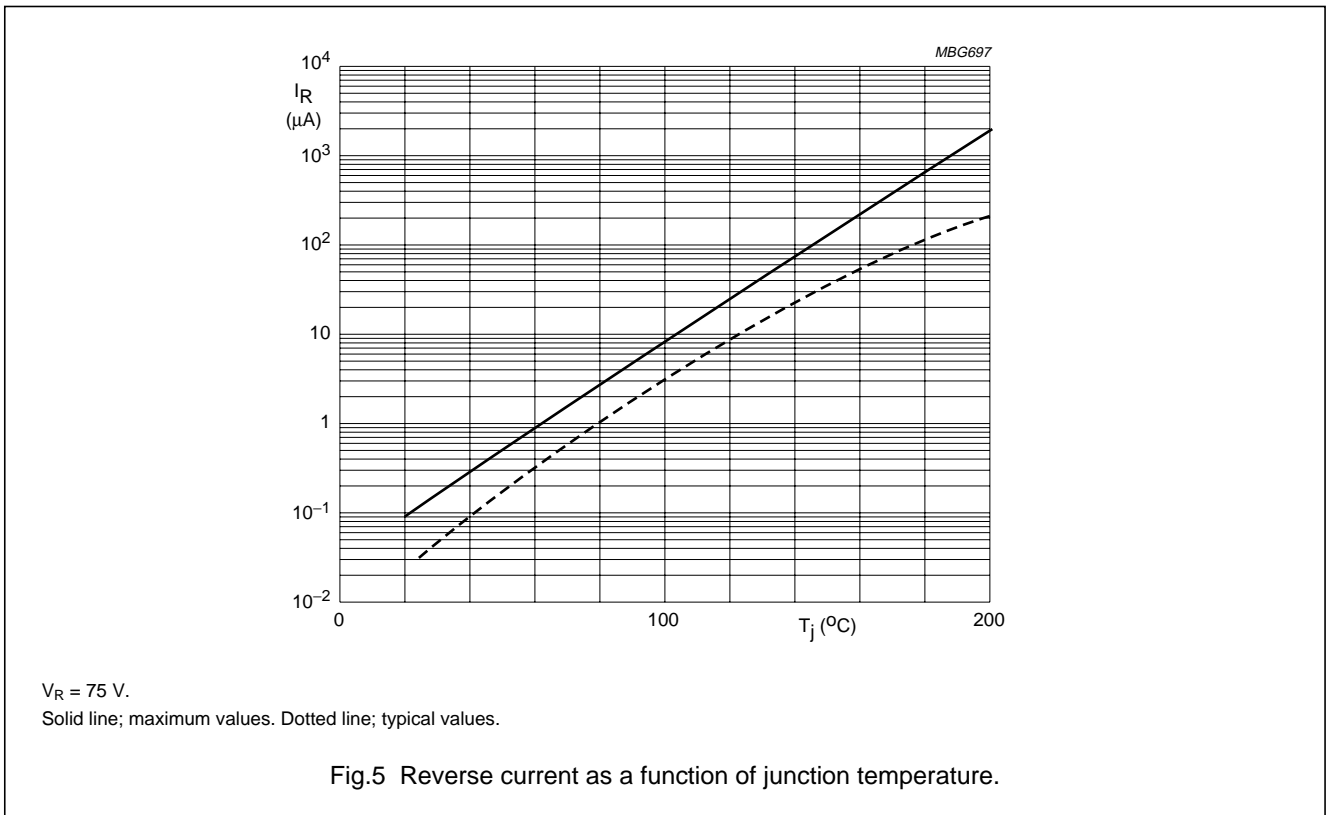
BAX18

GRAPHICAL DATA



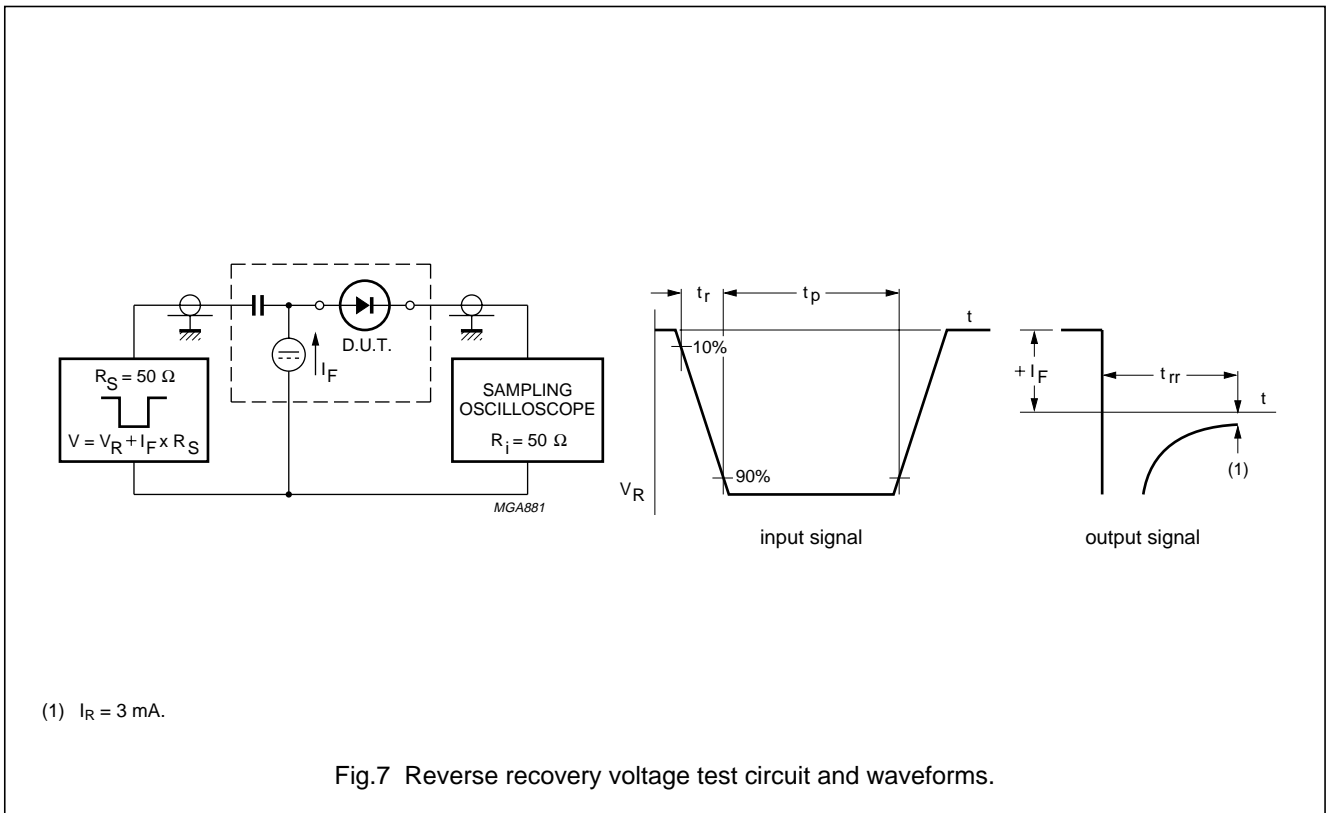
General purpose diode

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General purpose diode

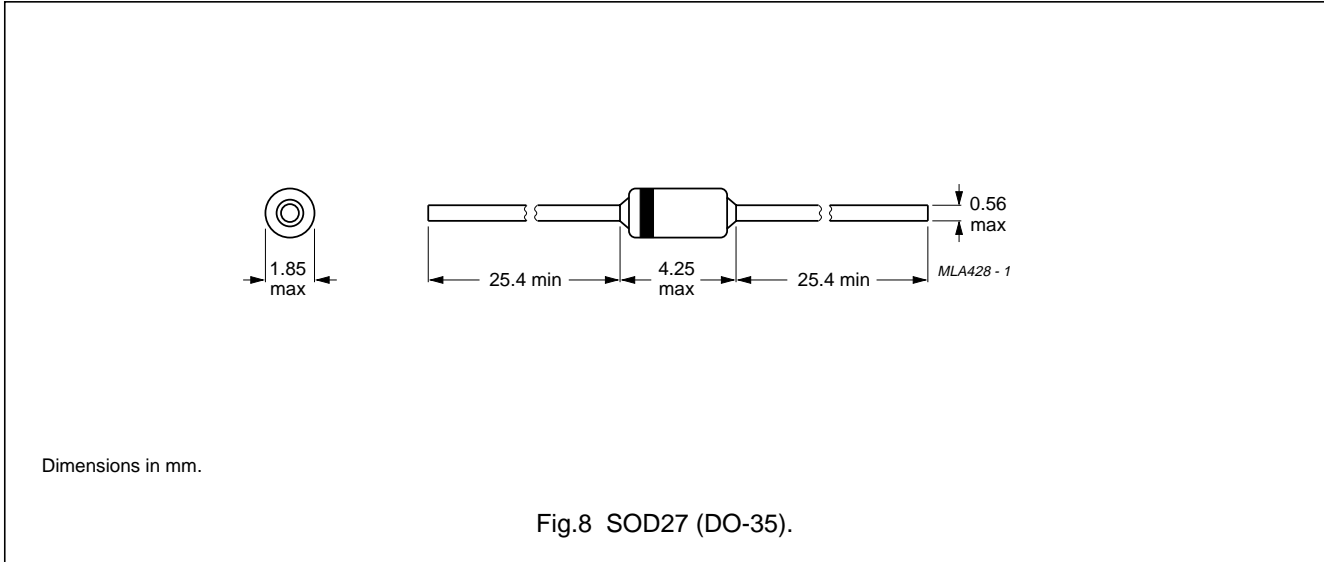
BAX18



General purpose diode

BAX18

PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

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